NSN 5961-01-580-6887

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-580-6887 **Inclosure Material:** Plastic **Overall Length:** Between 0.249 inches and 0.263 inches **Terminal Length:** 0.069 inches **Overall Height:** Between 0.060 inches and 0.068 inches **Overall Width:** Between 0.130 inches and 0.145 inches **Function For Which Designed: Amplifier End Application:** Vhf fm/fh; general hellenic staff **Mounting Facility Quantity: Mounting Method:** Slot **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to emitter voltage, dc **Current Rating Per Characteristic:** 1.00 amperes collector current, dc **Power Rating Per Characteristic:** 1.5 watts total power dissipation **Product Name:** Medium power npn silicon high current transistor surface mount **Special Features:** Lea (pb) free; npn silicon epitaxial transistor; 1000/tape and reel; operating and storage temp range: m65.0/p150.0 degrees c **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No